

Thin Film PID Field Failures and Root Cause Determination

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Outline

- ▶ Field Data
- ▶ Laboratory measurements on return modules
- ▶ Degradation model
- ▶ Verification
- ▶ Acceleration factors
- ▶ Manufacturing excursions
- ▶ Fixing the problem

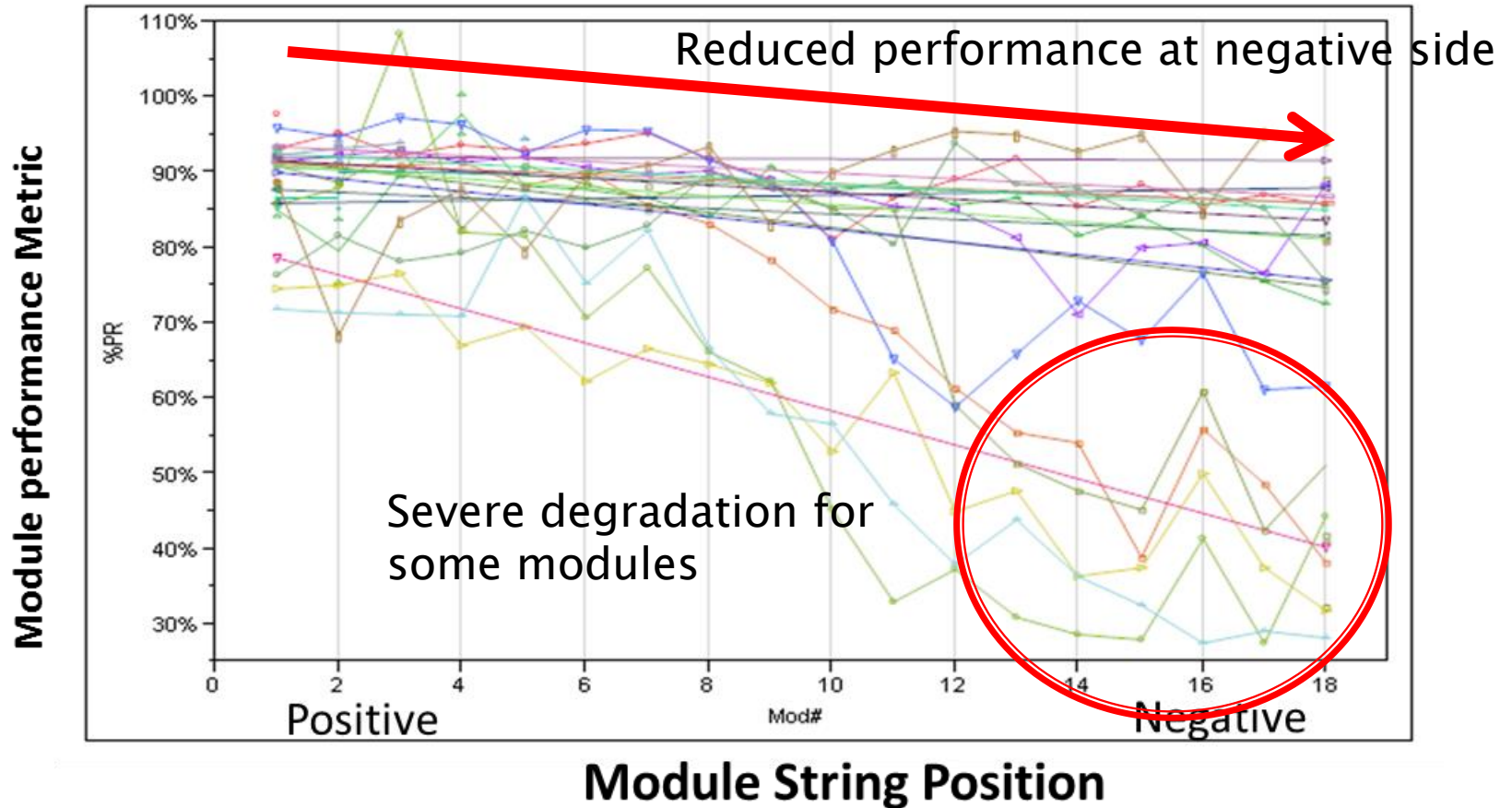


Field

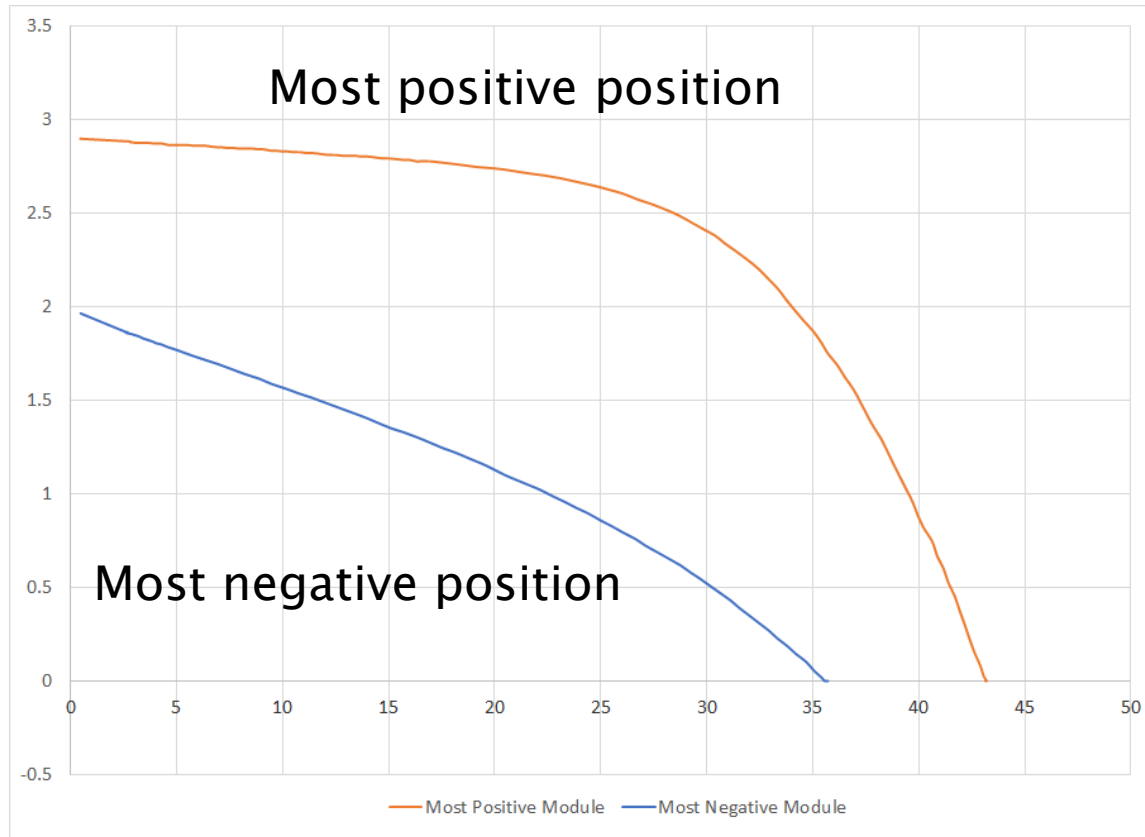
- ▶ Location: Germany
 - ▶ Size: 3 MW
 - ▶ Inverter: Transformer less
 - ▶ Voltage: 1 000 V
 - ▶ Grounding: Ungrounded
 - ▶ Modules: Thin Film (CdTe)
-
- ▶ Issue: Substantial under performance after 1 year of operation



Field Measurements



Return Module I-V



Severe degradation in Rsh is the issue



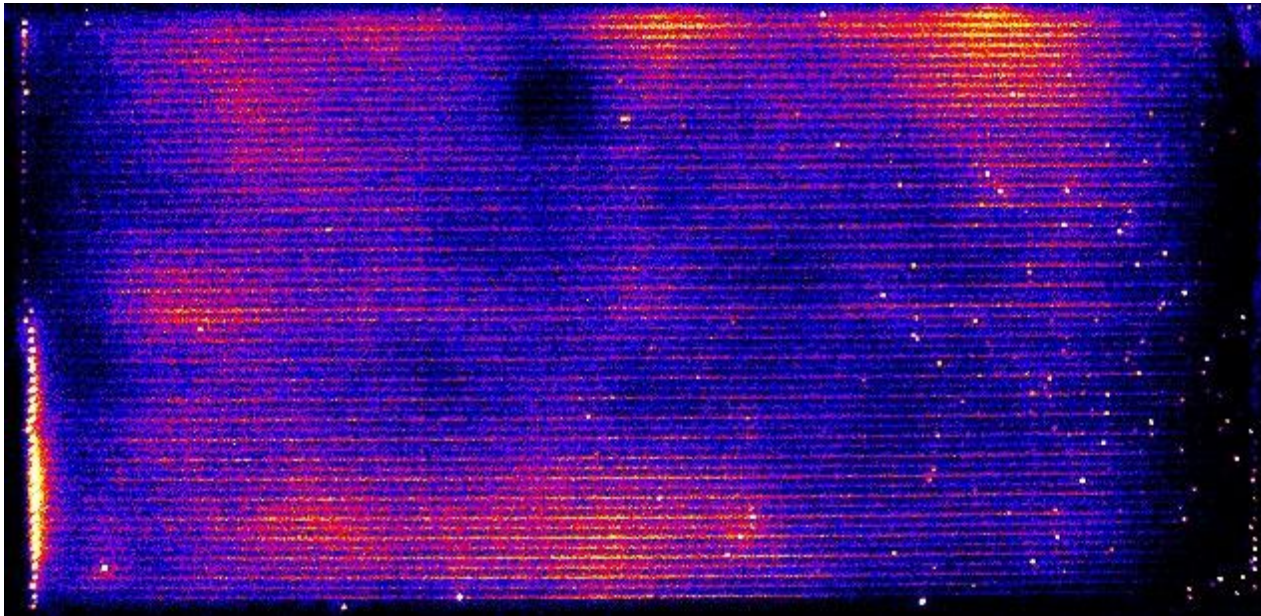
Additional tests on return modules

- ▶ HiPot: pass
- ▶ H₂O ingress: none
- ▶ Delam inspection: none



Lock-In thermography

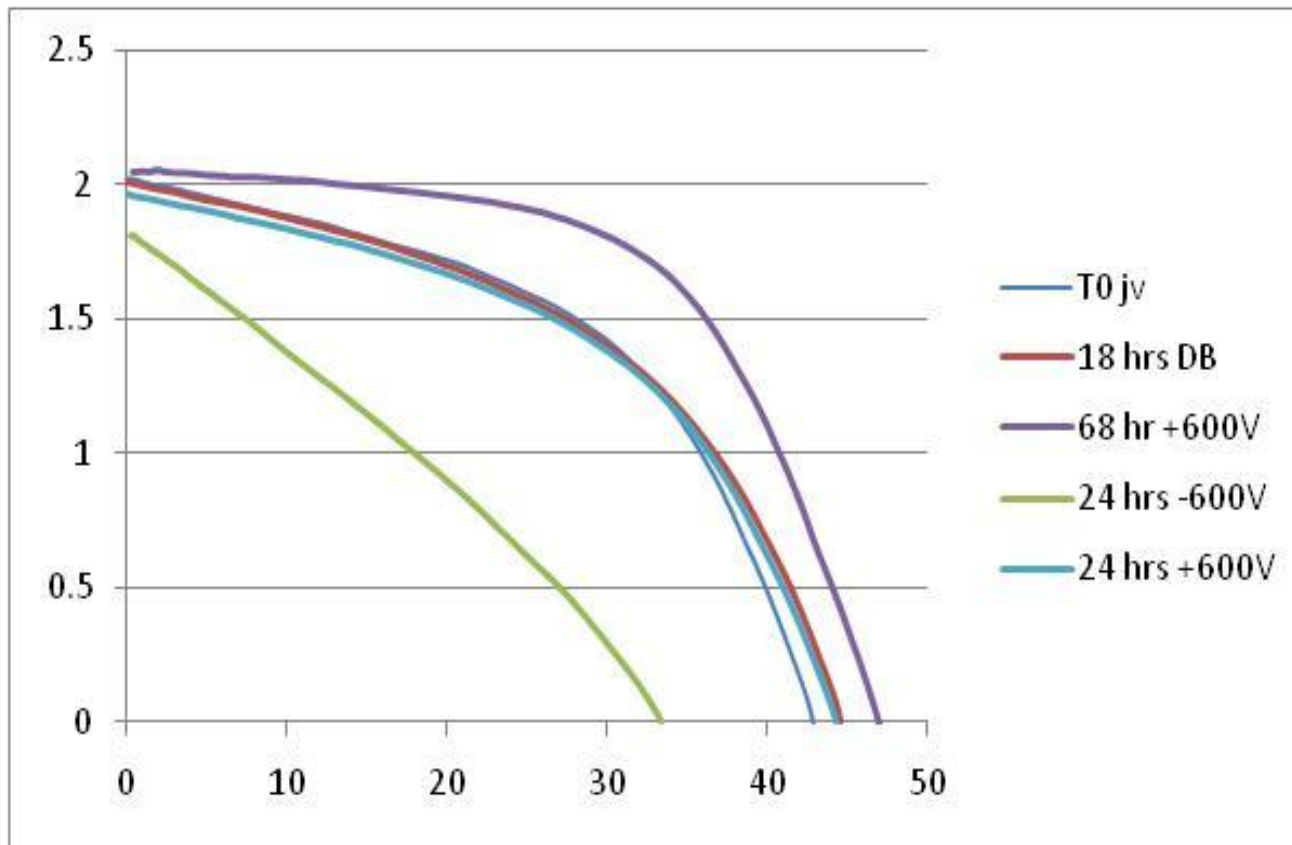
Pinpointing the location of shunts



Severe scribe
shunts in degraded
module



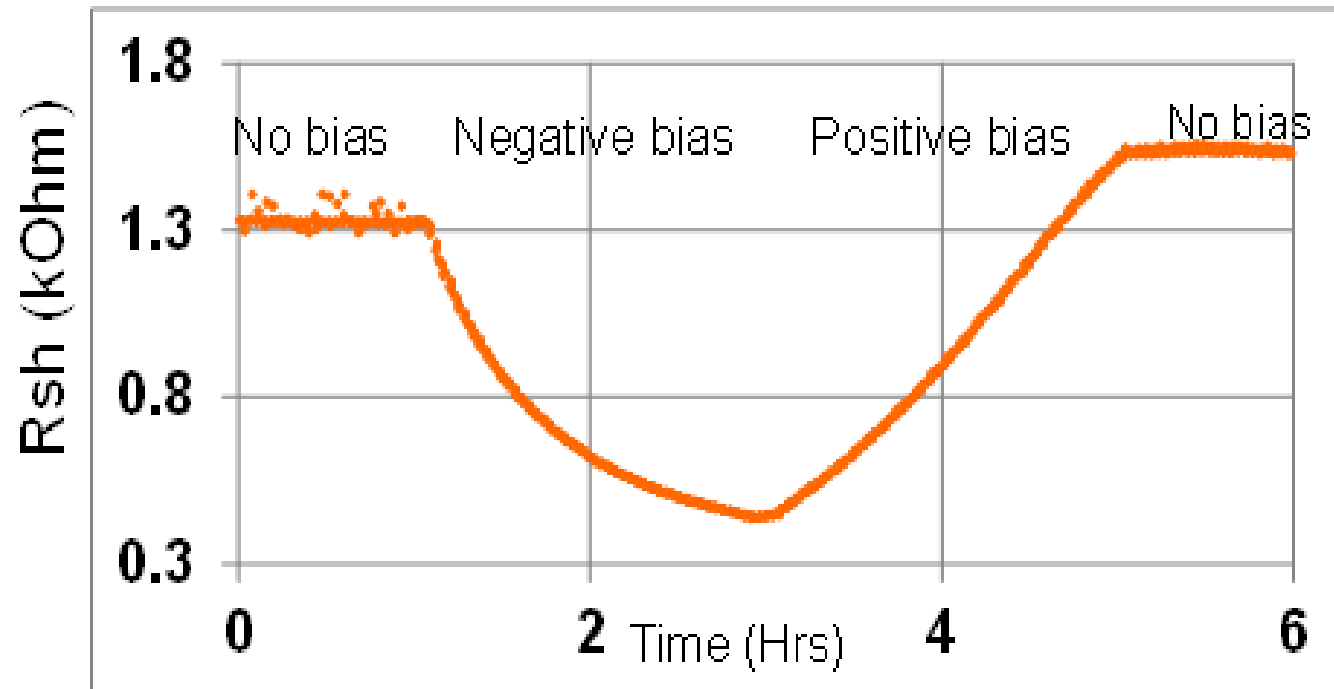
Reversibility of damage



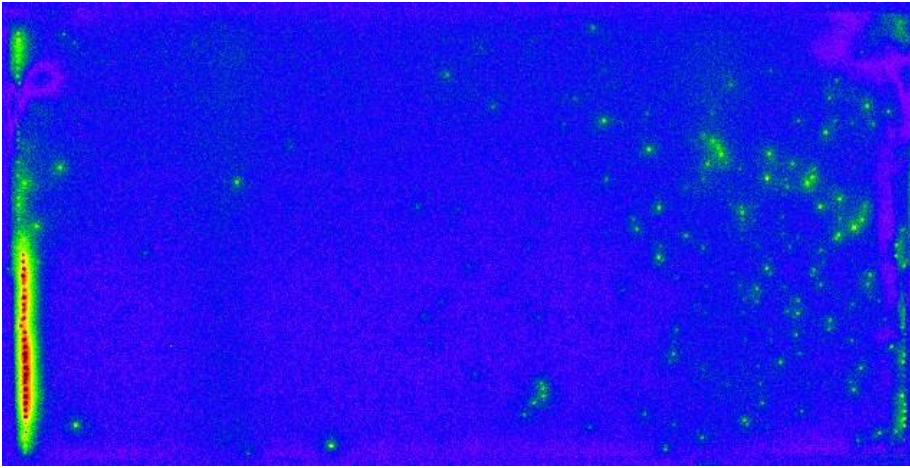
Main degradation is in Rsh and it is a reversible PID type



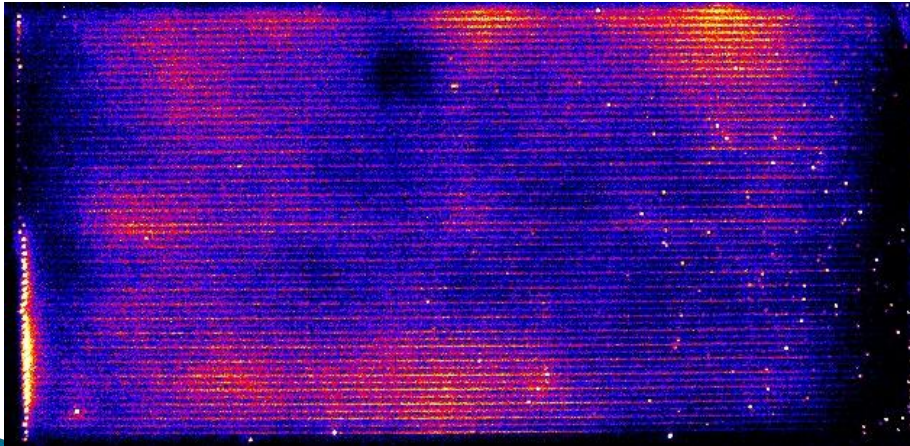
Laboratory PID test on “virgin” modules



Lock-in thermography of healed module



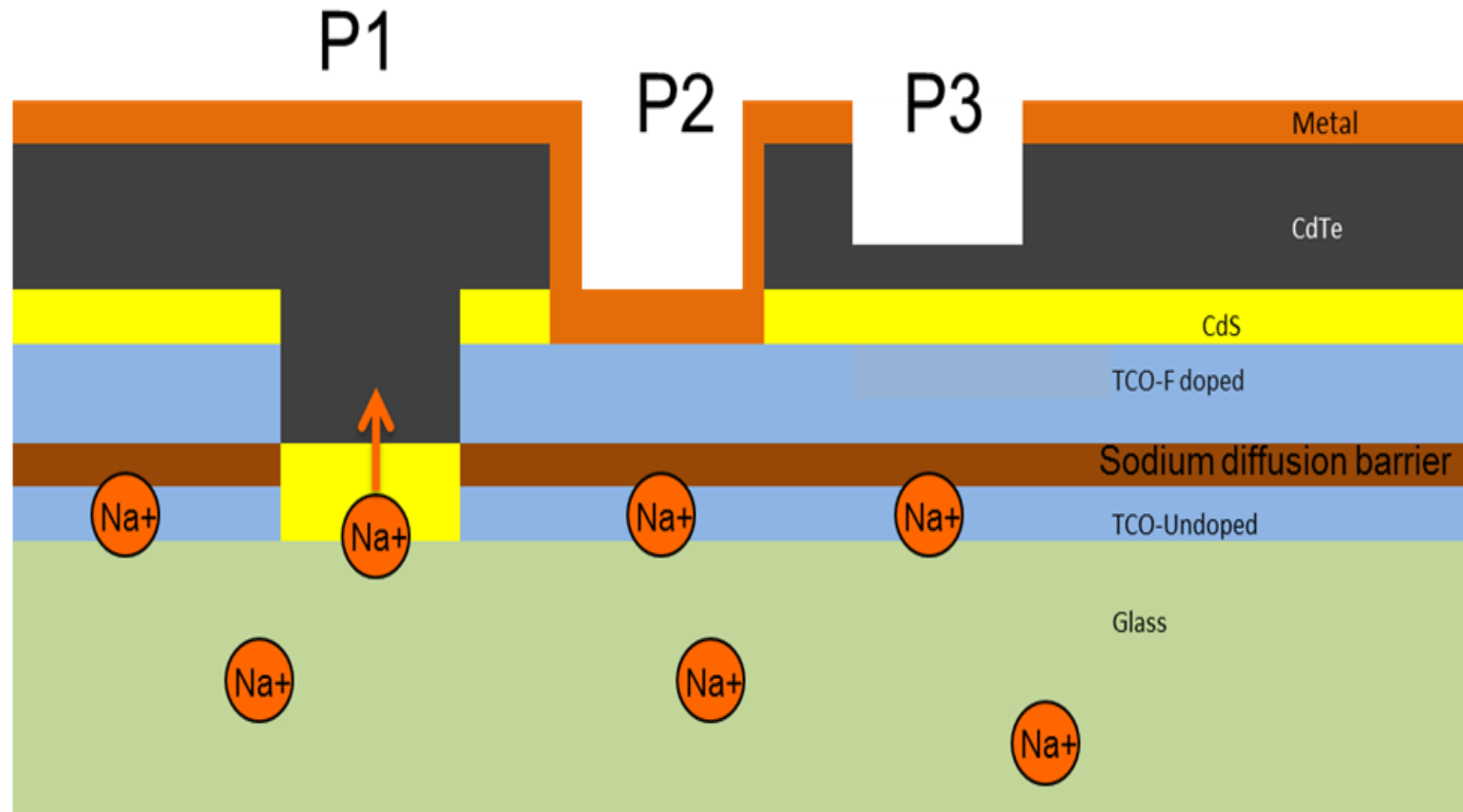
After positive bias healing



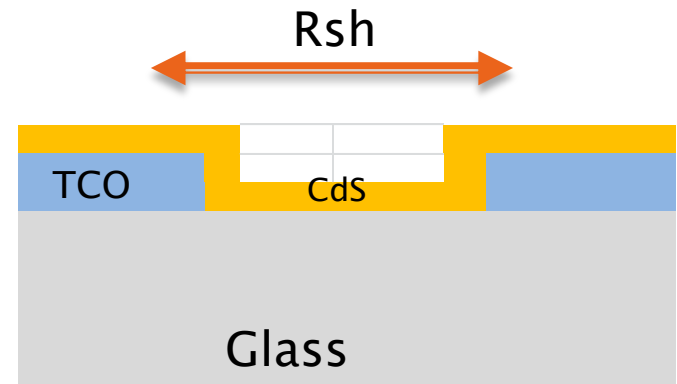
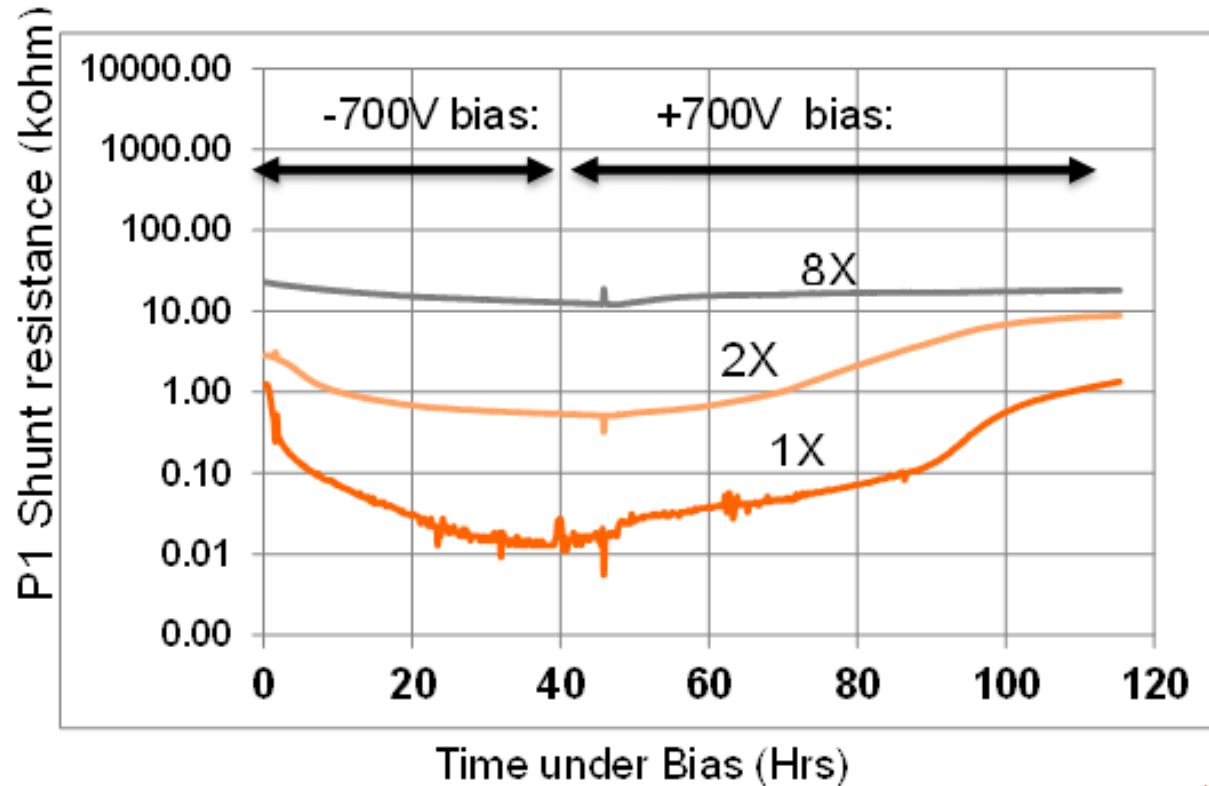
Before



Degradation Model



Verification experiments



Acceleration Factors

Time for P1 shunt resistance to drop 50%

	No Bias	-750V
41C	?	~20 hrs
57C	40 hrs	3.5 hrs
77C	8 hrs	0.5 hrs

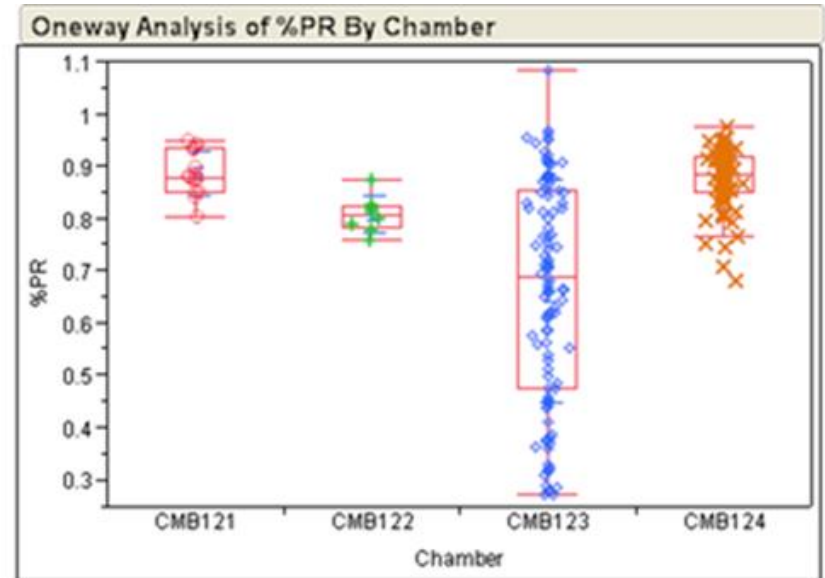
Both temperature and voltage are strong drivers



Severely Degraded Modules: manufacturing excursions

All the severely degraded modules came from only one of 4 production chambers and only from a specific time period.

Root cause:
Broken glass on top of heater coils in the deposition chamber: Excellent source of sodium.



Missing Rows 31

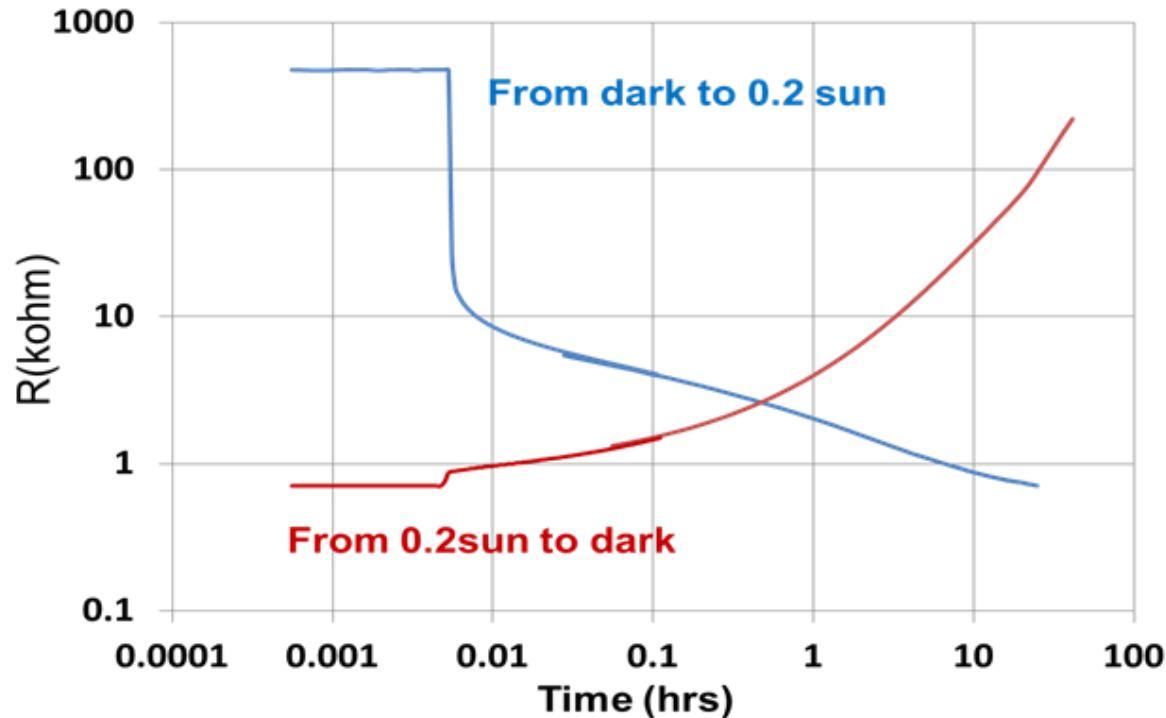
Excluded Rows 59

Means and Std Deviations

Level	Number	Mean	Std Dev	Std Err		
				Mean	Lower 95%	Upper 95%
CMB121	14	0.887643	0.043081	0.01151	0.86277	0.91252
CMB122	8	0.810250	0.034997	0.01237	0.78099	0.83951
CMB123	105	0.662857	0.212916	0.02078	0.62165	0.70406
CMB124	79	0.876544	0.056592	0.00637	0.86387	0.88922



Photoconductivity in CdS



CdS photoconductivity is very dynamic and may take many Hrs to fully develop



Conclusions

- ▶ We have characterized a new type of reversible PID caused by field assisted diffusion of mobile ions into the P1 scribe lines in thin film modules.

It is a bad idea to leave semiconductor material in the P1 scribe.

- ▶ Corrective Action
 - Switch P1 scribe and semi deposition process order
 - Backfill P1 with inert material



Thank You